

High Voltage Standard Rectifier

R	3~ Rectifier				
V_{RRM}	=	2200 V			
IDAV	=	90 A			
I _{FSM}	=	370 A			

Half 3~ Bridge, Common Cathode

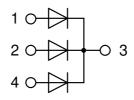
Part number

DNA90YC2200NA



Backside: isolated





Features / Advantages:

- Planar passivated chips
- Very low leakage currentVery low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
 Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

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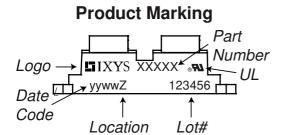


Rectifier					Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V _{RSM}	max. non-repetitive reverse bloc	cking voltage	$T_{VJ} = 25^{\circ}C$			2300	V	
V_{RRM}	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			2200	V	
I _R	reverse current	V _R = 2200 V	$T_{VJ} = 25^{\circ}C$			100	μΑ	
		$V_R = 2200 \text{ V}$	$T_{VJ} = 150$ °C			1.5	mA	
V _F	forward voltage drop	I _F = 30 A	$T_{VJ} = 25^{\circ}C$			1.23	V	
		$I_F = 90 A$				1.70	٧	
		$I_F = 30 \text{ A}$	$T_{VJ} = 125$ °C			1.21	V	
		$I_F = 90 A$				1.85	٧	
I DAV	bridge output current	$T_C = 85^{\circ}C$	$T_{VJ} = 150$ °C			90	Α	
		rectangular d = ⅓						
V _{F0}	threshold voltage	deservate della servica	$T_{VJ} = 150$ °C			0.86	V	
r _F	slope resistance \(\) for power	loss calculation only				11.4	mΩ	
R _{thJC}	thermal resistance junction to ca	ase				1.2	K/W	
R _{thCH}	thermal resistance case to heats	sink			0.1		K/W	
P _{tot}	total power dissipation		$T_{C} = 25^{\circ}C$			100	W	
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			370	Α	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			400	Α	
		t = 10 ms; (50 Hz), sine	T _{vJ} = 150°C			315	Α	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			340	Α	
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			685	A ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			665	A²s	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150$ °C			495	A ² s	
		t = 8.3 ms; (60 Hz), sine	$V_R = 0 V$			480	A²s	
CJ	junction capacitance	$V_R = 700 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		7		pF	
				+	-	+		



DNA90YC2200NA

Package SOT-227B (minibloc)				Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					150	Α
T _{VJ}	virtual junction temperature				-40		150	°C
T _{op}	operation temperature				-40		125	°C
T _{stg}	storage temperature				-40		150	°C
Weight						30		g
M _D	mounting torque				1.1		1.5	Nm
$\mathbf{M}_{\scriptscriptstyleT}$	terminal torque				1.1		1.5	Nm
d _{Spp/App}	creepage distance on surface striking distance through air		3.2			mm		
d _{Spb/Apb}	creepage distance on surra	ce striking distance through air	terminal to backside	8.6	6.8			mm
V _{ISOL}	isolation voltage	t = 1 second			3000			٧
.002		t = 1 minute	50/60 Hz, RMS; lisoL ≤ 1 mA		2500			٧



Part description

D = Diode N = High Voltage Standard Rectifier

A = (>= 2000V)

90 = Current Rating [A]

YC = Half 3~ Bridge, Common Cathode

2200 = Reverse Voltage [V]

NA = SOT-227B (minibloc)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DNA90YC2200NA	DNA90YC2200NA	Tube	10	513723

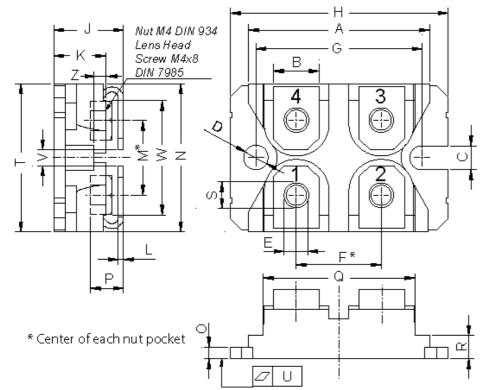
Similar Part	Package	Voltage class	
DNA90YA2200NA	SOT-227B (minibloc)	2200	

Equivalent Circuits for Simulation		* on die level	$T_{VJ} = 150^{\circ}C$	
$I \rightarrow V_0$)—[R ₀]-	Rectifier		
V _{0 max}	threshold voltage	0.86		V
R _{0 max}	slope resistance *	9.5		mΩ





Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches		
DIIII.	min	max	min	max	
Α	31.50	31.88	1.240	1.255	
В	7.80	8.20	0.307	0.323	
С	4.09	4.29	0.161	0.169	
D	4.09	4.29	0.161	0.169	
Е	4.09	4.29	0.161	0.169	
F	14.91	15.11	0.587	0.595	
G	30.12	30.30	1.186	1.193	
Н	37.80	38.23	1.488	1.505	
J	11.68	12.22	0.460	0.481	
K	8.92	9.60	0.351	0.378	
L	0.74	0.84	0.029	0.033	
M	12.50	13.10	0.492	0.516	
N	25.15	25.42	0.990	1.001	
0	1.95	2.13	0.077	0.084	
Р	4.95	6.20	0.195	0.244	
Q	26.54	26.90	1.045	1.059	
R	3.94	4.42	0.155	0.167	
S	4.55	4.85	0.179	0.191	
Т	24.59	25.25	0.968	0.994	
U	-0.05	0.10	-0.002	0.004	
V	3.20	5.50	0.126	0.217	
W	19.81	21.08	0.780	0.830	
Z	2.50	2.70	0.098	0.106	

